

Hi-Speed USB and Audio Switches with Negative Signal Capability and High-Voltage-Tolerable VBUS Detection

General Description

The MAX14585/MAX14585A high-ESD-protected doublepole/double-throw (DPDT) switches multiplex Hi-Speed (480Mbps) USB and analog signals such as AC-coupled audio or video. These devices combine the low oncapacitance (C_{ON}) and low on-resistance (R_{ON}) necessary for high-performance switching applications in portable electronics and include an internal negative supply to pass audio signals that swing below ground down to -1.8V. The devices also handle USB low-/full-speed signaling and operate from a 2.7V to 5.5V supply.

The devices feature a V_{BUS} detection input (V_B) that can handle voltage up to 28V to automatically switch to the USB signal path upon detection of a valid V_{BUS} signal (V_{B} > V_{VBDET}). In a dead battery situation, the voltage on V_B can supply power to the part if V_B is greater than 4.5V. The MAX14585 features internal shunt resistors on the audio path to reduce clicks and pops heard at the output.

The MAX14585/MAX14585A are available in a spacesaving, 10-pin, 1.4mm x 1.8mm UTQFN package and operate over the -40°C to +85°C temperature range.

Applications

Cell Phones PDAs and Handheld Devices Tablet PCs

Benefits and Features

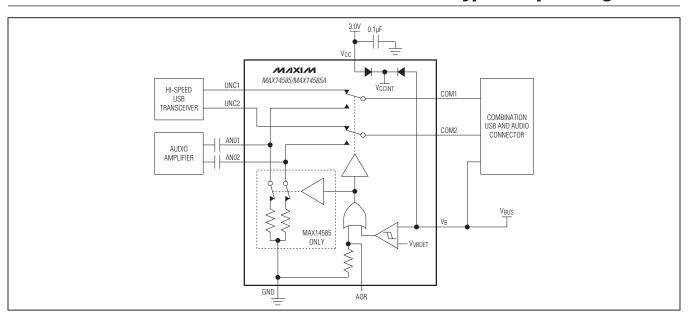
- **♦ Low Power Consumption**

 - ♦ Single 2.7V to 5.5V Supply Operation, V_{CC}
- ♦ Flexible Design
 - ♦ Dual Power-Supply Architecture, V_B and V_{CC}
 - ♦ ANO_ Channel Override Control Input
- **♦** High Level of Integration for Performance
 - ♦ 28V-Capable V_B Input with Automatic UNC_ Selection by V_{BUS} Detection
 - ♦ Low-Capacitance Hi-Speed USB for Both Channels (UNC_ and ANO_)
 - ♦ Distortion-Free Negative Signal Throughput Down to -1.8V on ANO_ Channel
 - \diamond 3 Ω (typ) On-Resistance
 - ♦ 960MHz Bandwidth
 - ♦ 0.04% THD+N Audio Channel
 - COM1, COM2
- ♦ Saves Board Space
 - ♦ Internal Shunt Resistor Reduces Clicks and Pops (MAX14585)
 - ♦ 10-Pin, 1.4mm x 1.8mm UTQFN Package

Ordering Information appears at end of data sheet.

For related parts and recommended products to use with this part, refer to www.maxim-ic.com/MAX14585.related.

Typical Operating Circuit



NIXIN

Maxim Integrated Products 1

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ABSOLUTE MAXIMUM RATINGS

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

PACKAGE THERMAL CHARACTERISTICS (Note 1)

Junction-to-Ambient Thermal Resistance (0,JA) 143.2°C/W Junction-to-Case Thermal Resistance (θ_{JC})......20.1°C/W

Note 1: Package thermal resistances were obtained using the method described in JEDEC specification JESD51-7, using a fourlayer board. For detailed information on package thermal considerations, refer to www.maxim-ic.com/thermal-tutorial.

ELECTRICAL CHARACTERISTICS

 $(T_A = -40^{\circ}\text{C to } +85^{\circ}\text{C}, \text{ unless otherwise noted. Typical values are at V}_{CC} = 3\text{V}, T_A = +25^{\circ}\text{C}.)$ (Note 2)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
POWER SUPPLY						
Power-Supply Range	V _{CC}		2.7		5.5	V
Supply Current	I _{SUPPLY}	$V_{CC} = 4.2V, 0V < V_{AOR} < 0.4V,$ $V_{AOR} \ge 1.4V$		7	14	μΑ
Power-Supply Rejection Ratio	PSRR	$f = 10kHz, V_{CC} = 3.0 \pm 0.3V,$ $R_{COM} = 50\Omega$		100		dB
V _B Detect Threshold	V _{VBDET}	V _{BUS} rising, V _{CC} ≥ 2.7V	3	3.3	3.6	V
V _B Detect Hysteresis	V _{VBDET_H}	V_{BUS} falling, $V_{CC} \ge 2.7V$		0.2		V
V _B Detect Leakage Current		V _B = 5.5V			40	μΑ
ANALOG SWITCH						
Analog-Signal Range	V _{UNC} _	V _{CC} ≥ 2.7V for UNC_	0		min(3.6V, V _{CC})	V
	V _{ANO_} , V _{COM_}	V _{CC} ≥ 2.7V for ANO_, COM_	-1.8		min(3.6V, V _{CC})	
ANO_ On-Resistance	R _{ON(NO)}	V _{CC} = 3V, V _{ANO} = -1.5V, +1.5V I _{COM} = 10mA		3	6	Ω
UNC_ On-Resistance	Pacietanas	$V_{CC} = 3V$, $V_{UNC} = 0V$ to V_{CC} , $I_{COM} = 10$ mA		3	6	Ω
	R _{ON(NC)}	V _B = 4.5V, V _{CC} = 0V to 5.5V, V _{UNC} = 0V to 2.5V, V _{AOR} = 0V, I _{COM} = 10mA		3	6	52
ANO_ On-Resistance Match Between Channels	ΔR _{ON(NO)}	V _{CC} = 3V, V _{ANO} = 0V, I _{COM} = 10mA (Note 3)		0.2		Ω

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ELECTRICAL CHARACTERISTICS (continued)

 $(T_A = -40^{\circ}\text{C to } +85^{\circ}\text{C}, \text{ unless otherwise noted. Typical values are at } V_{CC} = 3V, T_A = +25^{\circ}\text{C.})$ (Note 2)

PARAMETER	SYMBOL	CO	ONDITIONS	MIN	TYP	MAX	UNITS
UNC_ On-Resistance Match Between Channels	ΔR _{ON(NC)}	V _{CC} = 3V, V _{UNC} = 0V, I _{COM} = 10mA (Note 3)			0.2		Ω
ANO_ On-Resistance Flatness	R _{FLAT(NO)}	V _{CC} = 3V, I _{COM} = 10mA, V _{ANO} = -1.5V to +1.5V (Note 4)			0.04	0.2	Ω
UNC_ On-Resistance Flatness	R _{FLAT(NC)}	V _{CC} = 3V, I _{COM} _ V _{CC} (Note 4)	= 10mA, V _{UNC} _= 0V to		0.04	0.2	Ω
Shunt Switch Resistance	R _{SH}	I _{ANO} = 2mA, V _C	C ≥ 2.7V		700	1300	Ω
AOR Pulldown Resistor	R _{AOR}			250		1200	kΩ
UNC_ Off-Leakage Current	IUNC_(OFF)	Switch open, V _{UN} V _{COM} = -1.5V, 2		-100		+100	nA
ANO_ Off-Leakage Current	I _{ANO_(OFF)}	MAX14585A, swit 0V, V _{COM} _ = 0V,	ch open, V _{ANO} _ = 2.5V, 2.5V, V _{CC} = 3V	-100		+100	nA
COM_ Off-Leakage Current	I _{COM_(OFF)}	$V_{CC} = 0V, V_{COM}$ $V_{UNC} = V_{ANO} = 0$		-10		+800	μΑ
COM_ On-Leakage Current		USB mode	V _{CC} = 3V, V _{ANO} = 0V, 2.5V, unconnected, V _{COM} = 0V, 2.5V	-200		+200	nA
	ICOM_(ON)	Audio mode	V _{CC} = 3V, V _{UNC} = 0V, 2.5V, unconnected, V _{COM} = -1.5V, 2.5V	-200		+200	nA
Turn-On Time	ton	ANO_ to COM_, Figure 1	$\begin{aligned} &V_{CC} = 3V, V_{ANO} = 1.5V, \\ &R_L = 50\Omega; V_{AOR} = 0V, \\ &V_B = 0V \text{ to 5V or } V_B = 5V, \\ &V_{AOR} = 0V \text{ to } V_{CC} \end{aligned}$		45	120	μs
		UNC_ to COM_, Figure 1	$V_{CC} = 3V$, $V_{UNC} = 1.5V$, $R_L = 50\Omega$; $V_{AOR} = 0V$, $V_B = 0V$ to $5V$		45	120	μs
Turn-Off Time	[†] OFF	ANO_ from COM_, Figure 1	$V_{CC} = 3V$, $V_{ANO} = 1.5V$, $R_L = 50\Omega$; $V_{AOR} = 0V$, $V_B = 0V$ to $5V$		8	40	μs
		UNC_ from COM_, Figure 1	$\begin{aligned} &V_{CC}=3V, V_{UNC}=1.5V,\\ &R_L=50\Omega; \ V_{AOR}=0V,\\ &V_B=0V \text{ to 5V or } V_B=5V,\\ &V_{AOR}=0V \text{ to } V_{CC} \end{aligned}$		8	40	μs
Break-Before-Make Time Delay	t _D	$R_L = 50\Omega$, time delay between one side of the switch open and the other side closed			28		μs
Output Skew (Same Switch)	t _{SK(P)}	Figure 2			40		ps
Output Skew Between Switches	t _{SK(O)}	Figure 2			40		ps
ANO_ Off-Capacitance	C _{NO_(OFF)}	$V_{ANO} = 0.5V_{P-P}$	DC bias = 0V, f = 1MHz		2.5		pF
UNC_ Off-Capacitance	C _{NC_(OFF)}	$V_{UNC_{-}} = 0.5 V_{P-P}$	DC bias = 0V, f = 1MHz		2.5		pF

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ELECTRICAL CHARACTERISTICS (continued)

 $(T_A = -40^{\circ}\text{C to } +85^{\circ}\text{C}, \text{ unless otherwise noted. Typical values are at V}_{CC} = 3\text{V}, T_A = +25^{\circ}\text{C}.)$ (Note 2)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
On-Capacitance	C _{COM_(ON)}	V_{COM} = 0.5 V_{P-P} , DC bias = 0V, f = 240MHz, R_L = 50 Ω		6.7		pF
AC PERFORMANCE						
ANO3dB Bandwidth	BW _{NO}	$R_S = R_L = 50\Omega$, $V_{ANO} = 0$ dBm, Figure 3		960		MHz
UNC3dB Bandwidth	BW _{NC}	$R_S = R_L = 50\Omega$, $V_{UNC} = 0$ dBm, Figure 3		960		MHz
Off-Isolation		$f = 100kHz$, $V_{COM} = 1V_{RMS}$, $R_L = 50\Omega$, Figure 3		-84		dB
Crosstalk		$f = 100kHz$, $V_{COM} = 1V_{RMS}$, $R_L = 50\Omega$, Figure 3 (Note 5)		-86		dB
Total Harmonic Distortion Plus Noise	THD+N	ANO_ to COM_, f = 20Hz to 20kHz, $V_{COM_} = 0.5V_{P-P}$, DC bias = 0V, $R_L = 600\Omega$	0.042		%	
LOGIC INPUT						
AOR Input Logic-High	V _{IH}	$V_{CC} \ge 2.7V$	1.4			V
AOR Input Logic-Low	V _{IL}	V _{CC} ≥ 2.7V			0.4	V
AOR Input Leakage Current	I _{IN}	$V_{AOR} = 0V \text{ or } V_{CC}, V_{CC} \ge 2.7V$	-22		+22	μΑ
ESD PROTECTION						
		Human Body Model		±15		
COM1, COM2		IEC 61000-4-2 Air Gap Discharge		±8		kV
		IEC 61000-4-2 Contact Discharge		±8		
All Other Pins		Human Body Model		±2	·	kV

- Note 2: All devices are 100% production tested at $T_A = +25^{\circ}$ C. Limits over the operating temperature range are guaranteed by design; not production tested.
- Note 3: $\Delta R_{ON(MAX)} = ABS(R_{ON(CH1)} R_{ON(CH2)})$. Note 4: Flatness is defined as the difference between the maximum and minimum value of on-resistance, as measured over specified analog-signal ranges.
- Note 5: Between two switches.

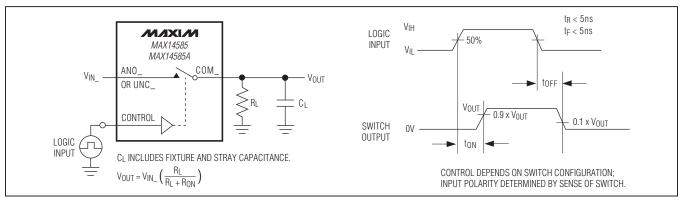


Figure 1. Switching Time

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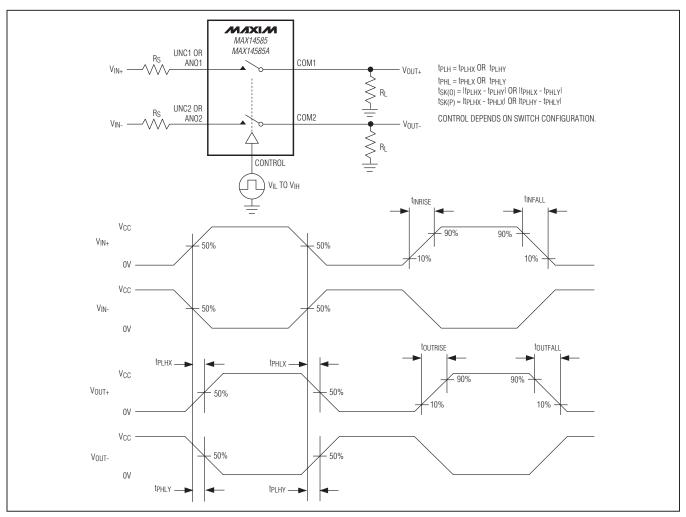


Figure 2. Output Skew

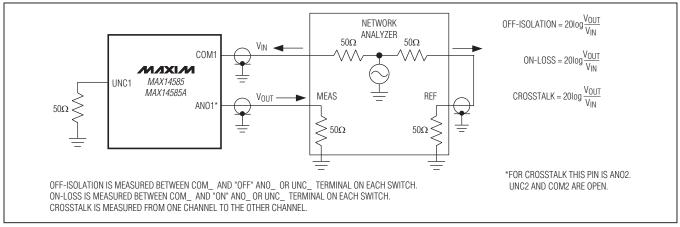
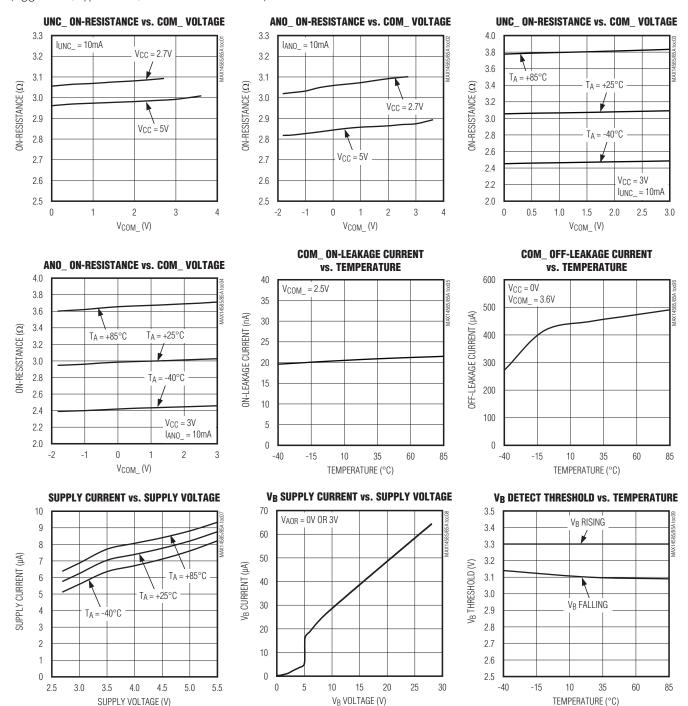


Figure 3. On-Loss, Off-Isolation, and Crosstalk

Hi-Speed USB and Audio Switches with Negative Signal Capability and High-Voltage-Tolerable VBUS Detection

Typical Operating Characteristics

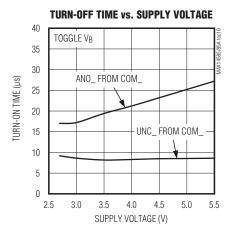
 $(V_{CC} = 3.0V, T_A = +25^{\circ}C, unless otherwise noted.)$

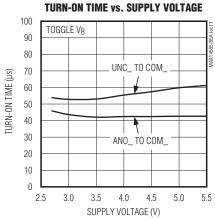


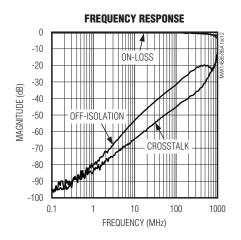
Hi-Speed USB and Audio Switches with Negative Signal Capability and High-Voltage-Tolerable VBUS Detection

Typical Operating Characteristics (continued)

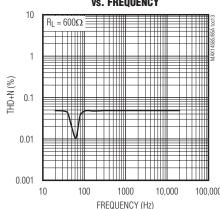
 $(V_{CC} = 3.0V, T_A = +25^{\circ}C, unless otherwise noted.)$

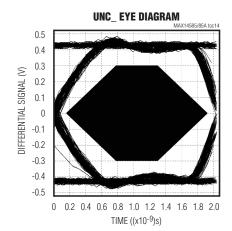






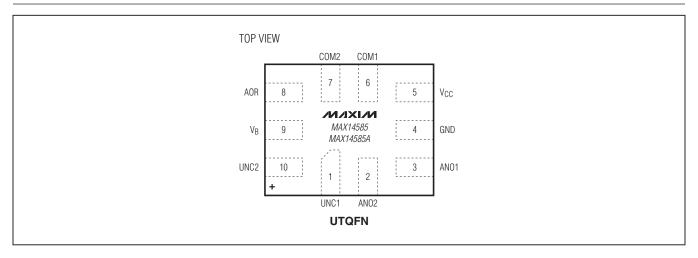
TOTAL HARMONIC DISTORTION PLUS NOISE vs. FREQUENCY





Hi-Speed USB and Audio Switches with Negative Signal Capability and High-Voltage-Tolerable VBUS Detection

Pin Configuration

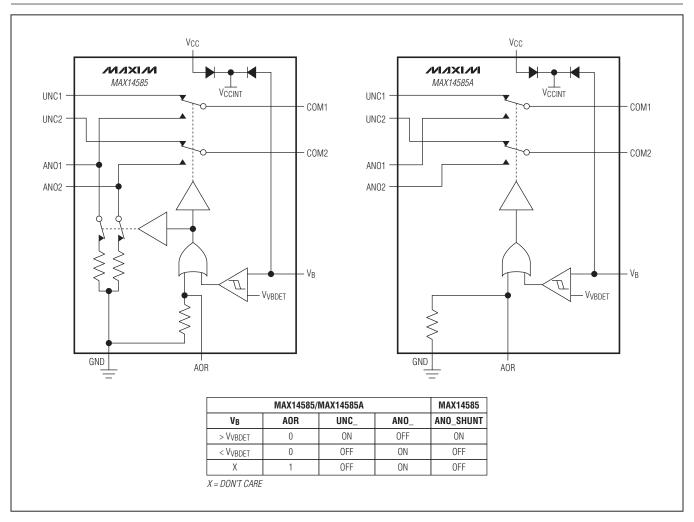


Pin Description

PIN	NAME	FUNCTION
1	UNC1	USB Input 1. Normally closed terminal for switch 1.
2	ANO2	Audio Input 2. Normally open terminal for switch 2.
3	ANO1	Audio Input 1. Normally open terminal for switch 1.
4	GND	Ground
5	V _{CC}	Positive Supply-Voltage Input. Bypass V_{CC} to GND with a 0.1 μ F capacitor as close as possible to the device.
6	COM1	Common Terminal for Switch 1
7	COM2	Common Terminal for Switch 2
8	AOR	Audio Override Input. Drive AOR low to have V _B control the switch. Drive AOR high to connect COM_ to ANO AOR has an internal pulldown resistor to GND.
9	V _B	V_{BUS} Detection Input. If $V_{B} \ge V_{VBDET}$, COM_ connects to UNC Otherwise, COM_ connects to ANO
10	UNC2	USB Input 2. Normally closed terminal for switch 2.

Hi-Speed USB and Audio Switches with Negative Signal Capability and High-Voltage-Tolerable VBUS Detection

Functional Diagrams/Truth Table



Detailed Description

The MAX14585/MAX14585A are high-ESD-protected single DPDT switches that operate from a 2.7V to 5.5V supply and are designed to multiplex Hi-Speed USB signals and AC-coupled analog signals. These switches combine the low on-capacitance (CON) and low on-resistance (R_{ON}) necessary for high-performance switching applications. These devices meet the requirements for USB low-speed and full-speed signaling. The negative signal capability of the analog channel allows signals below ground to pass through without distortion.

Analog-Signal Levels

The devices are bidirectional, allowing ANO_, UNC_, and COM_ to be configured as either inputs or outputs. Note that UNC_ and ANO_ are only protected against ESD up to ±2kV (HBM) and could require additional ESD protection if used as outputs. These devices feature a charge pump that generates a negative supply to allow analog signals as low as -1.8V to pass through ANO_ when V_{CC} supply is greater than 2.7V. This allows AC-coupled signals that drop below ground to pass when operating from a single power supply.

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When V_{CC} is below 2.7V and V_B is less than 4.5V, the switches accept signals from 0 to 3.6V but do not switch according to the Functional Diagrams/Truth Table.

V_{BUS} Detection Input

The devices feature a V_{BUS} detection input (V_B) that connects COM_ to UNC_ when V_B exceeds the V_{BUS} detection threshold (V_{VBDFT}). For applications where V_{BUS} is always present, drive the audio override input (AOR) high to connect ANO_ to COM_ (see the Functional Diagrams/Truth Table). Drive AOR low to have V_B control the switch position. Drive AOR rail-to-rail to minimize power consumption.

The V_B input is capable of handling voltage up to 28V for higher V_{BUS} application. In the case where the main power V_{CC} is lost due to an event such as a dead battery, V_B becomes the power supply if V_B is greater than 4.5V.

Click-and-Pop Suppression (MAX14585)

The switched 700Ω (typ) shunt resistors on the MAX14585 automatically discharge any capacitance at the ANO_ terminals when they are unconnected from COM_. This reduces audio click-and-pop sounds that can occur when switching between USB and audio sources.

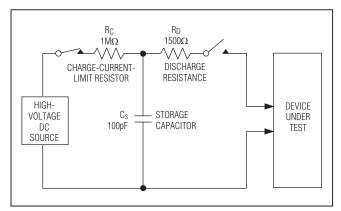


Figure 4. Human Body ESD Test Model

Applications Information

Extended ESD Protection

ESD protection structures are incorporated on all pins to protect against electrostatic discharges up to ±2kV (HBM) encountered during handling and assembly. COM1 and COM2 are further protected against ESD up to ±15kV (HBM) without damage. The ESD structures withstand high ESD in both normal operation and when the devices are powered down. After an ESD event, the devices continue to function without latchup.

ESD Test Conditions

ESD performance depends on a variety of conditions. Contact Maxim for a reliability report that documents test setup, test methodology, and test results.

Human Body Model

Figure 4 shows the HBM. Figure 5 shows the current waveform it generates when discharged into a lowimpedance state. This model consists of a 100pF capacitor charged to the ESD voltage of interest that is then discharged into the device through a $1.5k\Omega$ resistor.

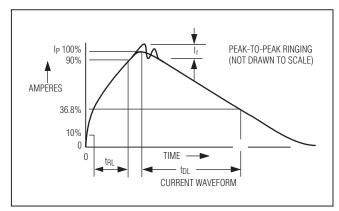


Figure 5. Human Body Current Waveform

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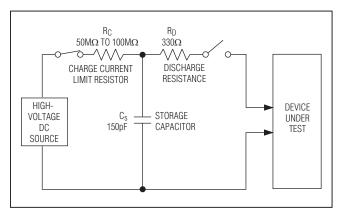


Figure 6. IEC 61000-4-2 ESD Test Model

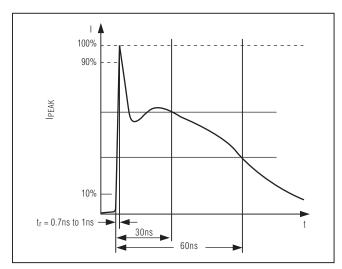


Figure 7. IEC 61000-4-2 ESD Generator Current Waveform

Chip Information

PROCESS: BICMOS

IEC 61000-4-2

The IEC 61000-4-2 standard covers ESD testing and performance of finished equipment. It does not specifically refer to integrated circuits. The major difference between tests done using the HBM and IEC 61000-4-2 is higher peak current in IEC 61000-4-2, because series resistance is lower in the IEC 61000-4-2 model. Hence, the ESD withstand voltage measured to IEC 61000-4-2 is generally lower than that measured using the HBM. Figure 6 shows the IEC 61000-4-2 model and Figure 7 shows the current waveform for the ±8kV, IEC 61000-4-2. Level 4, ESD Contact-Discharge Method.

Layout

Hi-Speed USB requires careful PCB layout with 45Ω single-ended/90 Ω differential controlled-impedance matched traces of equal lengths. Ensure that bypass capacitors are as close to the device as possible. Use large ground planes where possible.

Ordering Information/ Selector Guide

PART	TOP MARK	SHUNT RESISTOR	PIN- PACKAGE
MAX14585 EVB+T	AAY	Yes	10 UTQFN
MAX14585AEVB+T	AAZ	No	10 UTQFN

Note: All devices are specified over the -40°C to +85°C temperature range.

+Denotes a lead(Pb)-free/RoHS-compliant package.

T = Tape and reel.

Package Information

For the latest package outline information and land patterns (footprints), go to www.maxim-ic.com/packages. Note that a "+", "#", or "-" in the package code indicates RoHS status only. Package drawings may show a different suffix character, but the drawing pertains to the package regardless of RoHS status.

PACKAGE	PACKAGE	OUTLINE	LAND
TYPE	CODE	NO.	PATTERN NO.
10 UTQFN	V101A1CN+1	21-0028	

Hi-Speed USB and Audio Switches with Negative Signal Capability and High-Voltage-Tolerable VBUS Detection

Revision History

REVISION NUMBER	REVISION DATE	DESCRIPTION	PAGES CHANGED
0	5/11	Initial release	_

Maxim cannot assume responsibility for use of any circuitry other than circuitry entirely embodied in a Maxim product. No circuit patent licenses are implied. Maxim reserves the right to change the circuitry and specifications without notice at any time.